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**REPLY UNDER 37 CFR 1.116  
EXPEDITED PROCEDURE  
TECHNOLOGY CENTER 1700**

Attorney Docket No. 015675.P556

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Patent Application of:

**Hacene Lahreche, et al.**

Application No. 10/516,358

Filed: November 24, 2004

For: **METHOD FOR EPITAXIAL  
GROWTH OF A GALLIUM NITRIDE FILM  
SEPARATED FROM ITS SUBSTRATE**

Examiner: Matthew J. Song

Art Unit: 1792

Confirmation No. 2705

**AMENDMENT AND RESPONSE TO FINAL OFFICE ACTION**

Mail Stop AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action dated August 8, 2008, Applicants submit the following amendments and remarks: